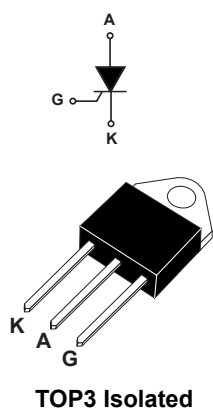


50 A 600 V SCR in TOP3 insulated



Features

- Max. repetitive blocking voltage: V_{DRM} , V_{RRM} = 600 V
- I_{GT} maximum = 80 mA
- ECOPACK®2 component (RoHS and HF compliance)
- Complies with UL 1557 standard (File ref : E81734)

Applications

- Solid state relays
- Welding equipment
- High power motor control
- Heating systems
- Controlled AC/DC bridge

Description

Available in a high power package TOP3-I, the BTW69-600 is suitable in applications where power handling and power dissipation are critical, such as solid state relays, welding equipment, high power motor control and power converters.

This device offers a superior performance in surge current handling capabilities, allowing usage in industrial environment.

Thanks to its internal ceramic pad, it provide high voltage insulation ($2500V_{RMS}$), complying with UL standards (file ref: E81734).

Product status link

[BTW69-600](#)

Product summary

$I_{T(RMS)}$	50 A
V_{DRM}/V_{RRM}	600 V
I_{GT}	80 mA

1 Characteristics

Table 1. Absolute maximum ratings

Symbol	Parameters			Value	Unit
$I_{T(RMS)}$	RMS on-state current (180° conduction angle)		$T_c = 75\text{ °C}$	50	A
$I_{T(AV)}$	Average on-state current (180° conduction angle)		$T_c = 75\text{ °C}$	32	A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25 °C, $V_R = 0\text{ V}$)		$t_p = 8.3\text{ ms}$	610	A
			$t_p = 10\text{ ms}$	580	
I^2t	I^2t value for fusing	$t_p = 10\text{ ms}$, $T_j = 25\text{ °C}$		1680	A ² s
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100\text{ ns}$	$F = 60\text{ Hz}$	$T_j = 125\text{ °C}$	50	A/ μ s
I_{GM}	Peak gate current	$t_p = 20\text{ }\mu$ s	$T_j = 125\text{ °C}$	8	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 125\text{ °C}$	1	W
T_{stg}	Storage junction temperature range			-40 to +150	°C
T_j	Operating junction temperature range			-40 to +125	°C
V_{GRM}	Maximum peak reverse gate voltage			5	V
V_{ins}	Insulation RMS voltage, 1 minute			2500	V

Table 2. Electrical characteristics ($T_j = 25\text{ °C}$, unless otherwise specified)

Symbol	Test conditions	T_j		Value	Unit
I_{GT}	$V_D = 12\text{ V}$, $R_L = 33\text{ }\Omega$		Min.	8	mA
			Max	80	
V_{GT}			Max	1.3	V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3\text{ k}\Omega$	125 °C	Min.	0.2	V
I_H	$I_T = 500\text{ mA}$, gate open		Max.	150	mA
I_L	$I_G = 1.2 \times I_{GT}$		Max.	200	mA
dV/dt	$V_D = 67\%$, V_{DRM} gate open	125 °C	Min.	1000	V/ μ s
V_{TM}	$I_{TM} = 100\text{ A}$, $t_p = 380\text{ }\mu$ s		Max.	1.9	V
V_{TO}	Threshold on-state voltage	125 °C	Max.	1.0	V
R_D	On-state dynamic resistance	125 °C	Max.	8.5	m Ω
I_{DRM}/I_{RRM}	$V_D = V_{DRM}$, $V_R = V_{RRM}$	25 °C	Max.	10	μ A
		125 °C		5	mA

Table 3. Thermal resistance

Symbol	Parameters	Value	Unit
$R_{th(j-c)}$	Junction to case (D.C)	0.9	$^{\circ}\text{C}/\text{W}$
$R_{th(j-a)}$	Junction to ambient (D.C)	50	

1.1 Characteristics (curves)

Figure 1. Maximum average power dissipation versus average on-state current

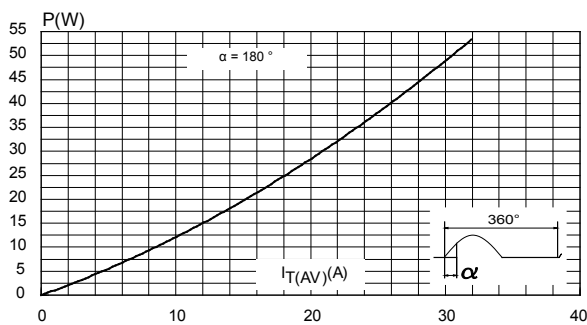


Figure 2. Average on-state current versus case temperature

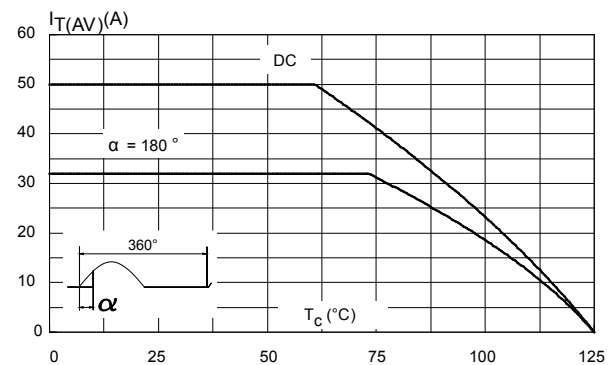


Figure 3. Relative variation of thermal impedance versus pulse duration

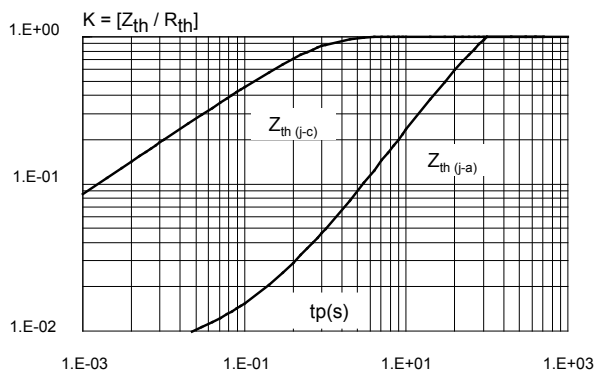


Figure 4. Relative variation of gate trigger current, holding current and latching current versus junction temperature

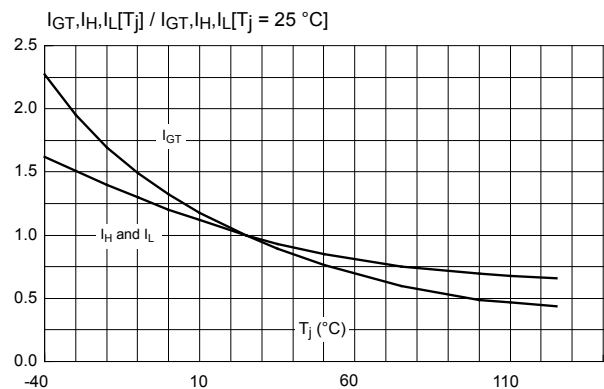


Figure 5. Surge peak on-state current versus number of cycles ($V_R = 0$ V)

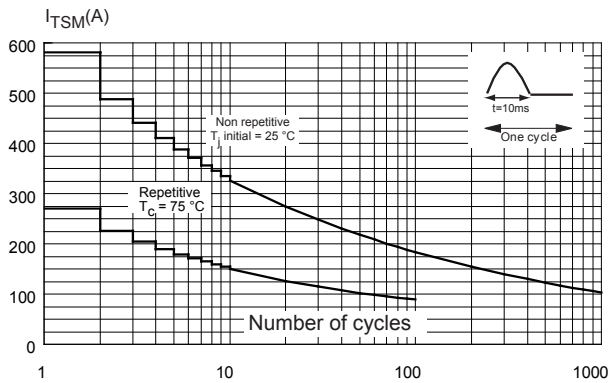


Figure 6. Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms, and corresponding value of I^2t ($V_R = 0$ V)

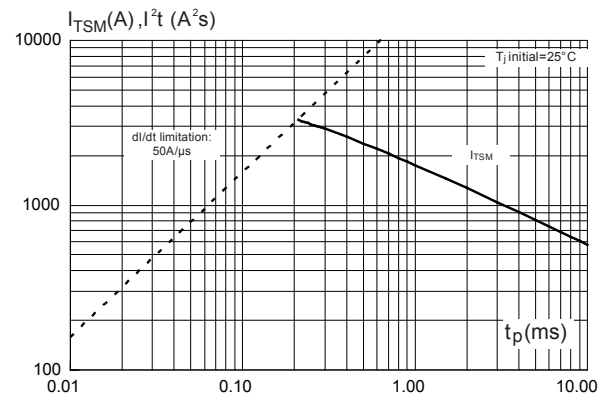
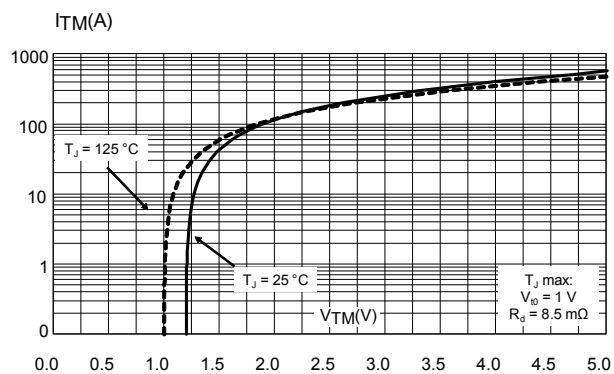


Figure 7. On-state characteristics (maximum values)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 TOP3 Ins. package information

- **ECOPACK®** (Lead-free plating and Halogen free package compliance)
- Lead-free package leads finishing
- Halogen-free molding compound resin meets UL94 standard level V0
- Recommended torque: 1.05 N·m (max. torque: 1.2 N·m)

Figure 8. TOP3 Isolated package outline

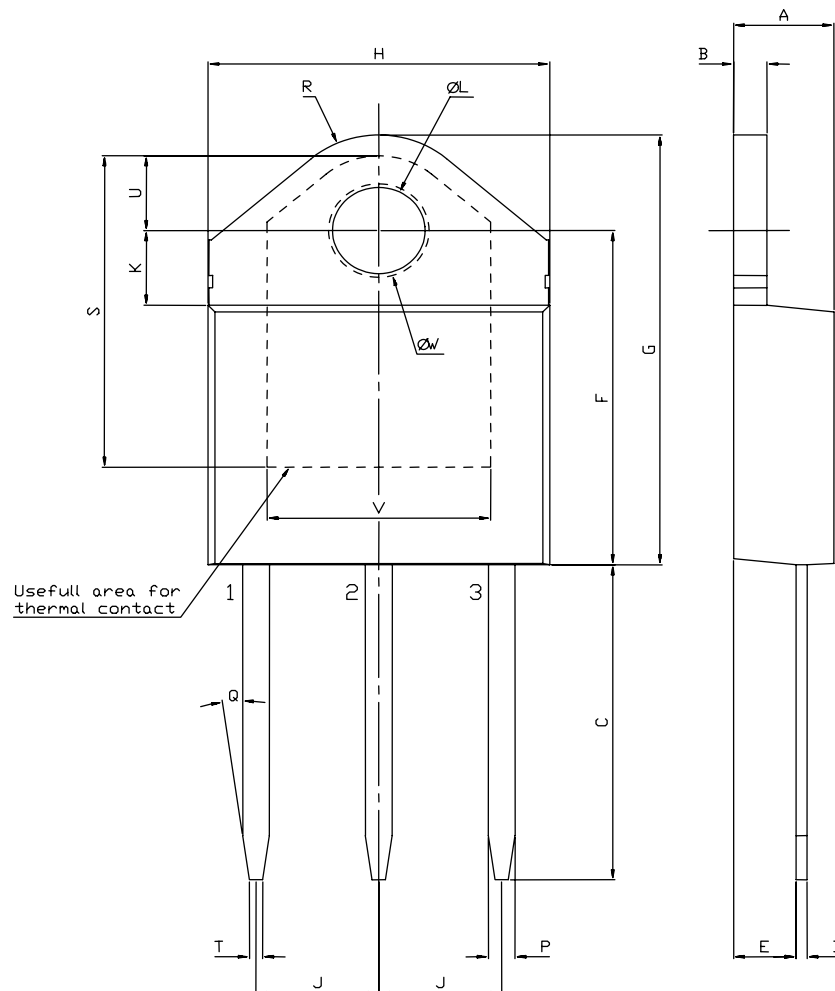


Table 4. TOP3 Isolated mechanical data

Ref.	Dimensions					
	mm			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.1732		0.1811
B	1.45		1.55	0.0571		0.0610
C	14.35		15.60	0.5650		0.6142
D	0.50		0.70	0.0197		0.0276
E	2.70		2.90	0.1063		0.1142
F	15.80		16.50	0.6220		0.6496
G	20.40		21.10	0.8031		0.8307
H	15.10		15.50	0.5945		0.6102
J	5.40		5.65	0.2126		0.2224
K	3.40		3.65	0.1339		0.1437
L	4.08		4.17	0.1606		0.1642
M	1.20		1.40	0.0472		0.0551
R		4.60			0.1811	

1. Inches given for reference only

3 Ordering information

Figure 9. Ordering information scheme

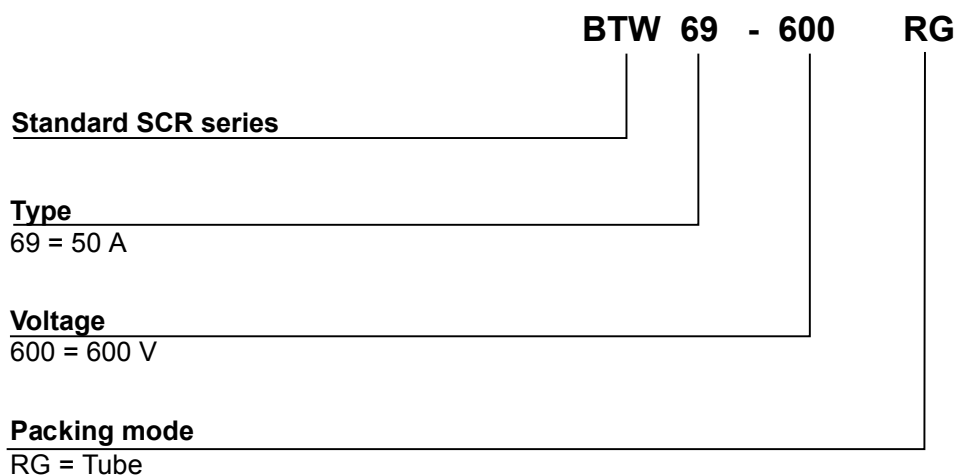


Table 5. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
BTW69-600RG	BTW69600	TOP3 Ins.	4.5 g	30	Tube

Revision history

Table 6. Document revision history

Date	Revision	Changes
09-Sep-2019	1	Initial release.

IMPORTANT NOTICE – PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. For additional information about ST trademarks, please refer to www.st.com/trademarks. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2019 STMicroelectronics – All rights reserved